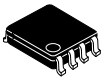
LVDS Single Port High Speed Repeater

FIN1101



SOIC8
CASE 751EB



US8
CASE 846AN

General Description

This single port repeater is designed for high speed interconnects utilizing Low Voltage Differential Signaling (LVDS) technology. It accepts and outputs LVDS levels with a typical differential output swing of 330 mV which provides low EMI at ultra low power dissipation even at high frequencies. It can directly accept multiple differential I/O including: LVPECL, HSTL, and SSTL−2 for translating directly to LVDS.

Features

- Up to 1.6 Gb/s Full Differential Path
- 3.5 ps Max Random Jitter and 135 ps Max Deterministic Jitter
- 3.3 V Power Supply Operation
- Wide Rail−To−Rail Common Mode Range
- Ultra Low Power Consumption
- LVDS Receiver Inputs Accept LVPECL, HSTL, and SSTL−2 Directly
- Power Off Protection
- 7 kV HBM ESD Protection (All Pins)
- Meets or Exceed the TA/EIA−644−A LVDS Standard
- Packaged in 8−Pin SOIC and US8
- Open Circuit Fail Safe Protection
- These Devices are Pb−Free, Halide Free and are RoHS Compliant

PIN DESCRIPTIONS

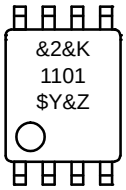
Pin Name	Description
R_{IN+}	Non−Inverting LVDS Inputs
R_{IN-}	Inverting LVDS Inputs
D_{OUT+}	Non−Inverting Driver Outputs
D_{OUT-}	Inverting Driver Outputs
EN	Driver Enable Pin
V_{CC}	Power Supply
GND	Ground

FUNCTION TABLE

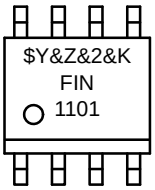
Inputs			Outputs	
EN	**R_{IN+}**	**R_{IN-}**	**D_{OUT+}**	**D_{OUT-}**
H	H	L	H	L
H	L	H	L	H
H	Fail Safe Case		H	L
L	X	X	Z	Z

H = HIGH Logic Level L = LOW Logic Level
X = Don't Care Z = High Impedance

MARKING DIAGRAM



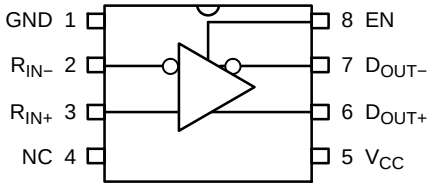
FIN1101K8X



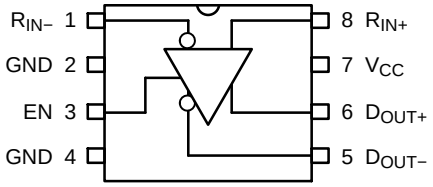
FIN1101MX

$Y = Logo
&Z = Assembly Plant Code
&2 = 2−Digit Date Code
&K = 2−Digits Lot Run Traceability Code
1101, FIN1101 = Specific Device Code

CONNECTION DIAGRAMS

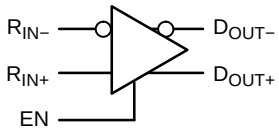


SOIC Package



US8 Package

FUCTIONAL DIAGRAM



ORDERING INFORMATION

See detailed ordering and shipping information on page 4 of this data sheet.

© Semiconductor Components Industries, LLC, 2002

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Rating
V_{CC}	Supply Voltage	−0.5 V to +4.6 V
V_{IN}	LVDS DC Input Voltage	−0.5 V to +4.6 V
V_{OUT}	LVDS DC Output Voltage	−0.5 V to +4.6 V
I_{OSD}	Driver Short Circuit Current	Continuous 10 mA
T_{STG}	Storage Temperature Range	−65°C to +150°C
T_J	Max Junction Temperature	150°C
T_L	Lead Temperature (Soldering, 10 seconds)	260°C
	ESD (Human Body Model)	7000 V
	ESD (Machine Model)	300 V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Value
V_{CC}	Supply Voltage	3.0 V to 3.6 V
T_A	Operating Temperature	−40°C to +85°C
$\|V_{ID}\|$	Magnitude of Input Differential Voltage	100 mV to V_{CC}
V_{IC}	Common Mode Input Voltage	(0 V + |VID| / 2) to (V_{CC} − $\|V_{ID}\|$ / 2)

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

DC ELECTRICAL CHARACTERISTICS (Over supply voltage and operating temperature ranges, unless otherwise specified)

Symbol	Parameter	Test Conditions	Min	Typ (Note 1)	Max	Unit
V_{TH}	Differential Input Threshold HIGH	See Figure 1; V_{IC} = +0.05 V, +1.2 V, or (V_{CC} − 0.05 V)	−	−	100	mV
V_{TL}	Differential Input Threshold LOW	See Figure 1; V_{IC} = +0.05 V, +1.2 V, or (V_{CC} − 0.05 V)	−100	−	−	mV
V_{IH}	Input High Voltage (EN)		2.0	−	V_{CC}	V
V_{IL}	Input Low Voltage (EN)		GND	−	0.8	V
V_{OD}	Output Differential Voltage	R_L = 100 Ω, Driver Enabled, See Figure 2	250	330	450	mV
ΔV_{OD}	V_{OD} Magnitude Change from Differential LOW−to−HIGH	R_L = 100 Ω, Driver Enabled, See Figure 2	−	−	25	mV
V_{OS}	Offset Voltage	R_L = 100 Ω, Driver Enabled, See Figure 2	1.125	1.23	1.375	V
ΔV_{OS}	Offset Magnitude Change from Differential LOW−to−HIGH	R_L = 100 Ω, Driver Enabled, See Figure 2	−	−	25	mV
I_{OS}	Short Circuit Output Current	D_{OUT+} = 0 V & D_{OUT-} = 0 V, Driver Enabled	−	−3.4	−6	mA
I_{OS}	Short Circuit Output Current	V_{OD} = 0 V, Driver Enabled	−	±3.4	±6	mA
I_{IN}	Input Current (EN, D_{INX+}, D_{INX-})	V_{IN} = 0 V to V_{CC}, Other Input = V_{CC} or 0 V (for Differential Inputs)	−	−	±20	μA
I_{OFF}	Power−Off Input or Output Current	V_{CC} = 0 V, V_{IN} or V_{OUT} = 0 V to 3.6 V	−	−	±20	μA
I_{CCZ}	Disabled Power Supply Current	Drivers Disabled	−	3.2	5.5	mA
I_{CC}	Power Supply Current	Drivers Enabled, Any Valid Input Condition	−	9.3	13.5	mA
I_{OZ}	Disabled Output Leakage Current	Driver Disabled, D_{OUT+} = 0 V to 3.6 V or D_{OUT-} = 0 V to 3.6 V	−	−	±20	μA
V_{IC}	Common Mode Voltage Range	$\|V_{ID}\|$ = 100 mV to V_{CC}	0 V + $\|V_{ID}\|$ / 2	−	V_{CC} − ($\|V_{ID}\|$ / 2)	V
C_{IN}	Input Capacitance	EN Input	−	2.2	−	pF
		Data Input	−	2.0	−	pF
C_{OUT}	Output Capacitance		−	2.6	−	pF

1. All typical values are at T_A = 25°C and with V_{CC} = 3.3 V.

AC ELECTRICAL CHARACTERISTICS (Over supply voltage and operating temperature ranges, unless otherwise specified)

Symbol	Parameter	Test Conditions	Min	Typ (Note 2)	Max	Unit
t_{PLHD}	Differential Propagation Delay LOW−to−HIGH	R_L = 100 Ω, C_L = 5 pF, V_{ID} = 200 mV to 450 mV, V_{IC} = $\|V_{ID}\|$ / 2 to (V_{CC} − (V_{ID} / 2), Duty Cycle = 50%, See Figure 3 and Figure 4	0.75	1.1	1.75	ns
t_{PHLD}	Differential Propagation Delay HIGH−to−LOW		0.75	1.1	1.75	ns
t_{TLHD}	Differential Output Rise Time (20% to 80%)		0.29	0.40	0.58	ns
t_{THLD}	Differential Output Fall Time (80% to 20%)		0.29	0.40	0.58	ns
$t_{SK(P)}$	Pulse Skew $\|t_{PLH} - t_{PHL}\|$		−	0.01	0.2	ns
$t_{SK(PP)}$	Part−to−Part Skew (Note 3)		−	−	0.5	ns
f_{MAX}	Maximum Frequency (Note 4) (Note 5)		400	800	−	MHz
t_{PZHD}	Differential Output Enable Time from Z to HIGH	R_L = 100 Ω, C_L = 5 pF, See Figure 2 and Figure 3	−	2.1	5	ns
t_{PZLD}	Differential Output Enable Time from Z to LOW		−	2.3	5	ns
t_{PHZD}	Differential Output Disable Time from HIGH to Z		−	1.5	5	ns
t_{PLZD}	Differential Output Disable Time from LOW to Z		−	1.8	5	ns
t_{DJ}	LVDS Data Jitter, Deterministic	V_{ID} = 300 mV, PRBS = 2^{23} − 1, V_{IC} = 1.2 V at 800 Mbps	−	85	135	ps
t_{RJ}	LVDS Clock Jitter, Random (RMS)	V_{ID} = 300 mV V_{IC} = 1.2 V at 400 MHz	−	2.1	3.5	ps

2. All typical values are at T_A = 25°C and with V_{CC} = 3.3 V, V_{ID} = 300 mV, V_{IC} = 1.2 V unless otherwise specified.
3. $t_{SK(PP)}$ is the magnitude of the difference in differential propagation delay times between identical channels of two devices switching in the same direction (either LOW−to−HIGH or HIGH−to−LOW) when both devices operate with the same supply voltage, same temperature, and have identical test circuits.
4. Passing criteria for maximum frequency is the output V_{OD} > 200 mV and the duty cycle is 45% to 55% with all channels switching.
5. Output loading is transmission line environment only; C_L is < 1 pF of stray test fixture capacitance.

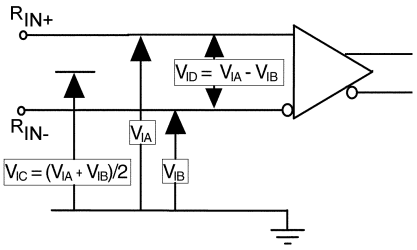


Figure 1. Differential Receiver Voltage Definitions and Propagation I and Transition Time Test Circuit

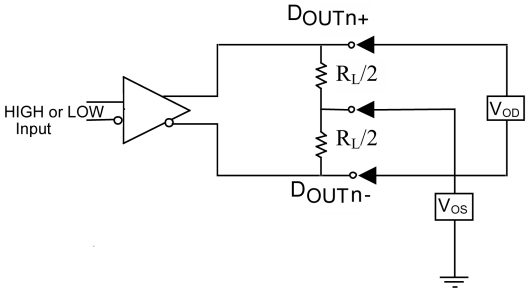
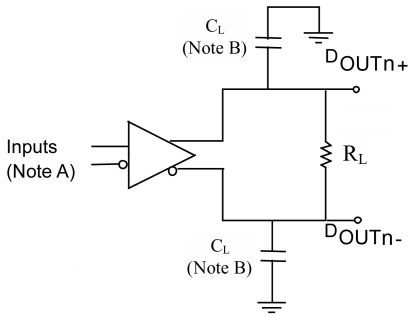


Figure 2. Differential Driver DC Test Circuit



Note A: All LVDS input pulses have frequency = 10 MHz, t_R or $t_F \leq$ 0.5 ns
Note B: C_L includes all probe and test fixture capacitances

Figure 3. Differential Driver Propagation Delay and Transition Time Test Circuit

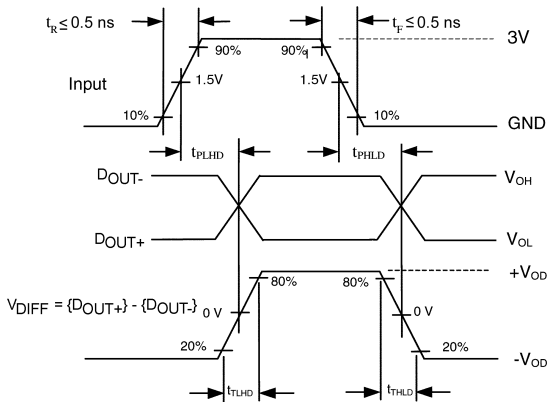
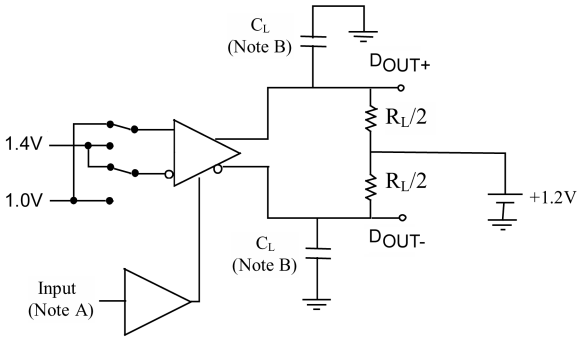


Figure 4. AC Waveforms



Note A: All LVTTL input pulses have frequency = 10 MHz, t_R or $t_F \leq 2$ ns
Note B: C_L includes all probe and test fixture capacitances

Figure 5. Differential Driver Enable and Disable Test Circuit

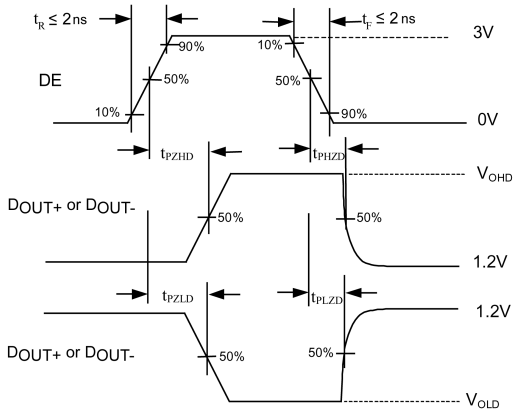


Figure 6. Enable and Disable AC Waveforms

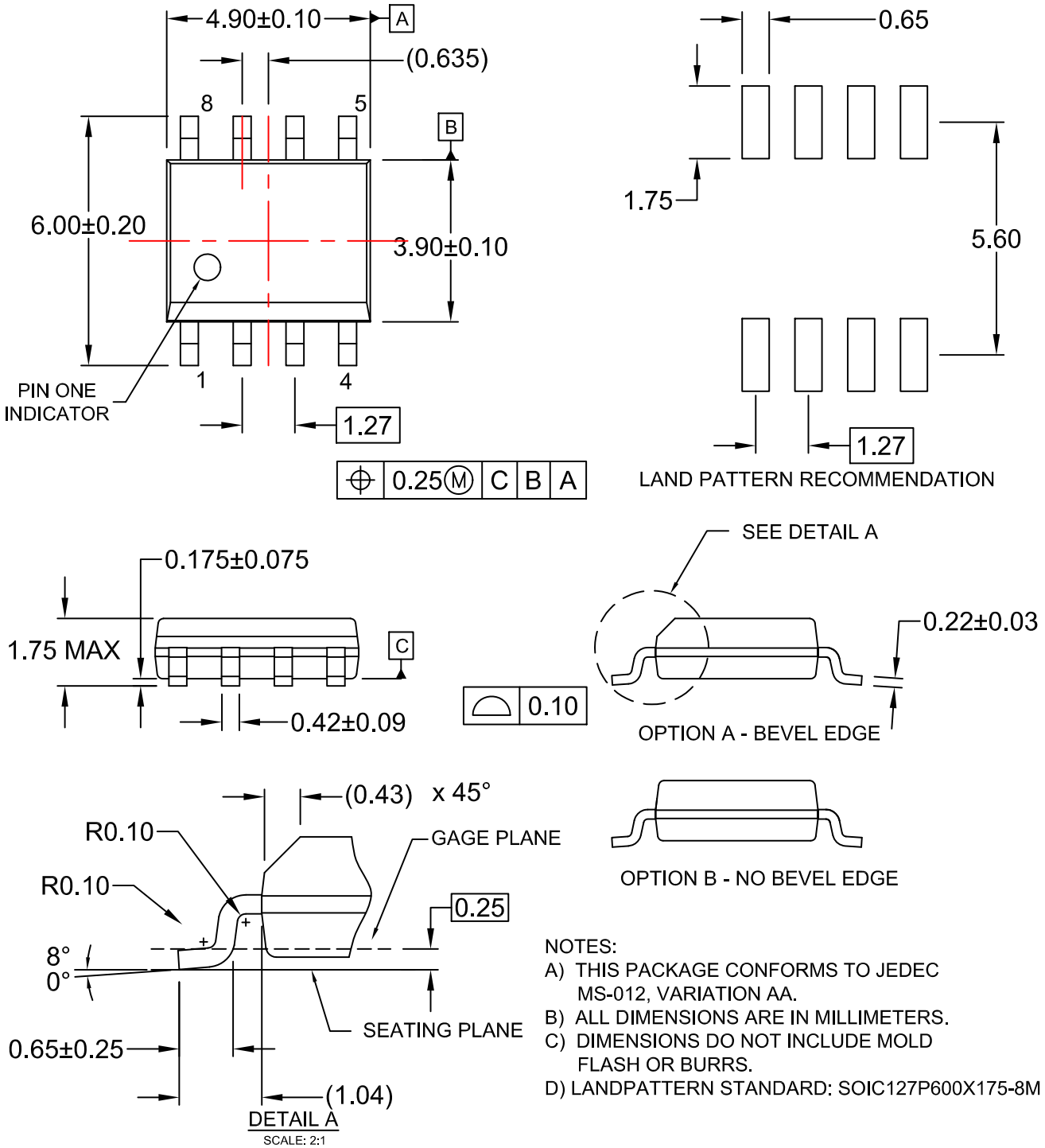
ORDERING INFORMATION

Order Number	Package Number	Package Description	Shipping†
FIN1101MX	M08A	8−Lead Small Outline Integrated Circuit (SOIC), JEDEC MS−012, 0.150” Narrow (Pb−Free)	2500 / Tape & Reel
FIN1101K8X	MAB08A	8−Lead US8, JEDEC MO−187, Variation CA 3.1 mm Wide (Pb−Free)	3000 / Tape & Reel

†For Information On Tape And Reel Specifications, Including Part Orientation And Tape Sizes, Please Refer To Our Tape And Reel Packaging Specifications Brochure, Brd8011/D.

SOIC8
CASE 751EB
ISSUE A

DATE 24 AUG 2017



NOTES:
A) THIS PACKAGE CONFORMS TO JEDEC MS-012, VARIATION AA.
B) ALL DIMENSIONS ARE IN MILLIMETERS.
C) DIMENSIONS DO NOT INCLUDE MOLD FLASH OR BURRS.
D) LANDPATTERN STANDARD: SOIC127P600X175-8M

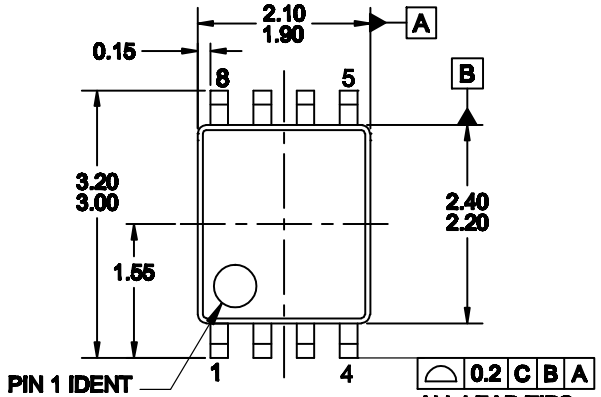
DOCUMENT NUMBER:	**98AON13735G**	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.
DESCRIPTION:	**SOIC8**	**PAGE 1 OF 1**

ON Semiconductor and ON are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.

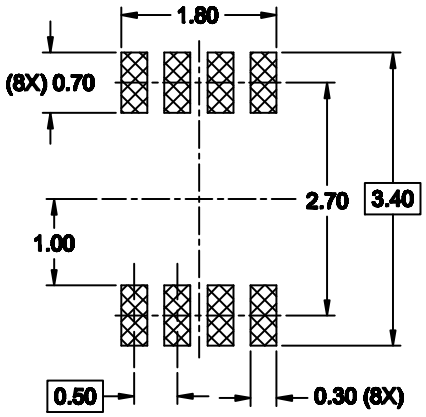
© Semiconductor Components Industries, LLC, 2019

US8
CASE 846AN
ISSUE O

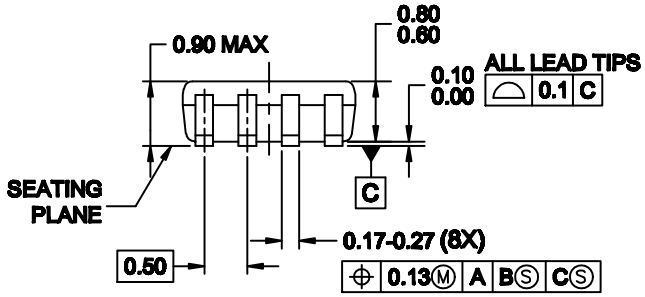
DATE 31 DEC 2016



TOP VIEW



RECOMMENDED LAND PATTERN



SIDE VIEW

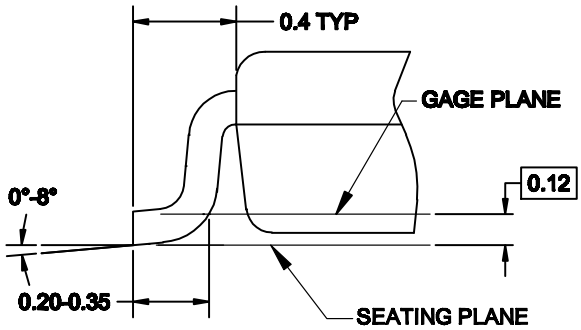
NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO-187

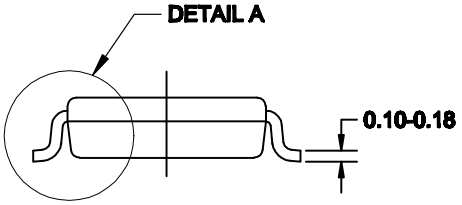
B. DIMENSIONS ARE IN MILLIMETERS.

C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.

D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1994.



DETAIL A



DOCUMENT NUMBER:	**98AON13778G**	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.	
DESCRIPTION:	**US8**		**PAGE 1 OF 1**

ON Semiconductor and ON are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.

© Semiconductor Components Industries, LLC, 2019

onsemi, , and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "**onsemi**" or its affiliates and/or subsidiaries in the United States and/or other countries. **onsemi** owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of **onsemi**'s product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent−Marking.pdf. **onsemi** reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as−is" and **onsemi** makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does **onsemi** assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using **onsemi** products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by **onsemi**. "Typical" parameters which may be provided in **onsemi** data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. **onsemi** does not convey any license under any of its intellectual property rights nor the rights of others. **onsemi** products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use **onsemi** products for any such unintended or unauthorized application, Buyer shall indemnify and hold **onsemi** and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that **onsemi** was negligent regarding the design or manufacture of the part. **onsemi** is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

ADDITIONAL INFORMATION

TECHNICAL PUBLICATIONS:
Technical Library: www.onsemi.com/design/resources/technical−documentation
onsemi Website: www.onsemi.com

ONLINE SUPPORT: www.onsemi.com/support
For additional information, please contact your local Sales Representative at www.onsemi.com/support/sales